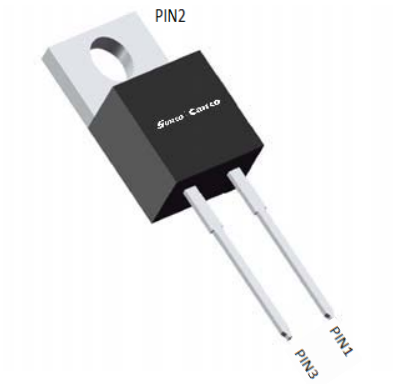
Ultra-Fast Recovery Diodes 10A FRED



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package**: TO-220AC
  Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity**: As marked

■Maximum Ratings (Tj=25℃ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1040
Device marking code			MUR1040
Repetitive Peak Reverse Voltage	V_{RRM}	V	400
Average Rectified Output Current @60Hz sine wave, R-load, Tc(FIG.1)	I_O	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Tj=25℃	I_{FSM}	A	120
Current Squared Time @1ms≤t≤8.3ms Tj=25℃,	I^2t	A^2s	60
Storage Temperature	T_{stg}	℃	-55 ~ +175
Junction Temperature	Tj	℃	-55 ~ +175
Typical Junction capacitance @4V,1MHz	Cj	pF	50

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS		Min	Typ	Max
Instantaneous forward voltage drop per diode	V_{FM}	V	I_{FM}=10.0A @Tj=25℃		-	1.15	1.30
			I_{FM}=10.0A @Tj=150℃			0.9	1.0
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	uA	V_{RM}=V_{RRM} Tj=25℃		-	-	5
	I_{RRM2}		V_{RM}=V_{RRM} Tj=150℃		-	40	100
Reverse Recovery Time	T_{RR}	ns	I_F=0.5A I_{RM}=1A I_{RR}=0.25A Tj=25℃		-	25	35
			Tj=25℃	I_F=10A di/dt=-200A/us V_{RM}=200V	-	30	-
			Tj=125℃		-	50	-
Peak recovery current	I_{RRM}	A	Tj=25℃		-	3.3	-
			Tj=125℃		-	6.8	-
Reverse recovery charge	Qrr	nC	Tj=25℃		-	50	-
			Tj=125℃		-	170	-

■Thermal Characteristics （Tj=25℃ Unless otherwise specified）

PARAMETER		SYMBOL	UNIT	MUR1040
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	℃/W	2.0
	Between junction and Air	$R_{\theta J-A}$	℃/W	50

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR1040	Approximate 1.8	50	1000	5000	Tube

■Characteristics (Typical)

FIG1:Io -Tc Curve

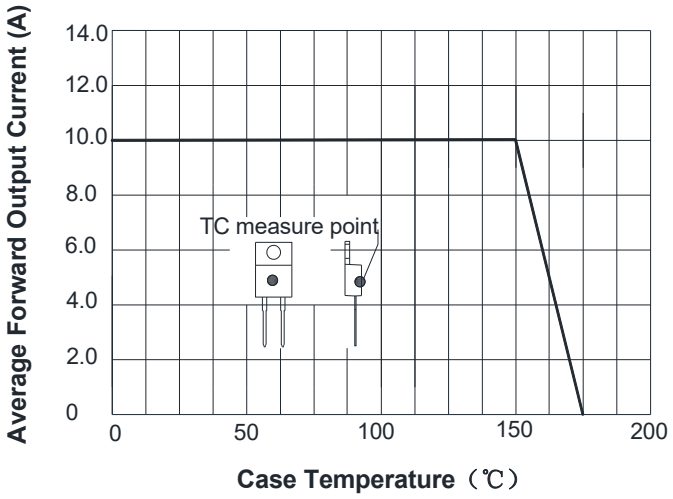


FIG2:Surge Forward Current Capability

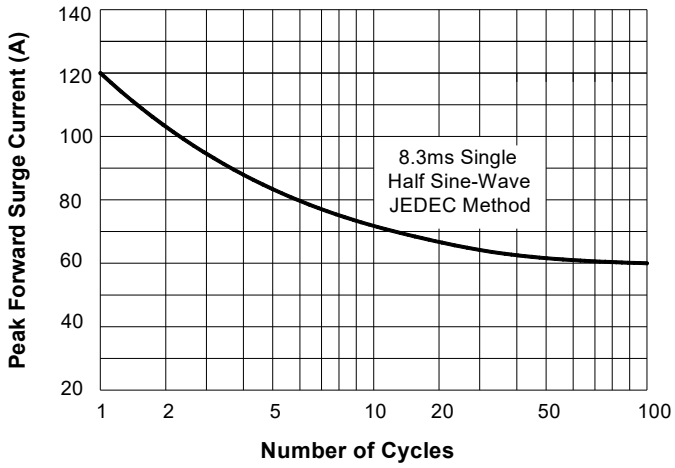


FIG3: Forward Voltage

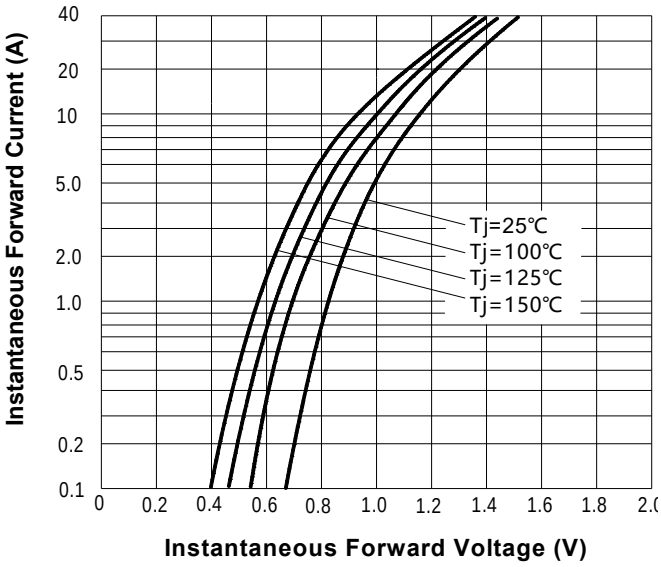


FIG.4: Instantaneous Reverse Characteristics

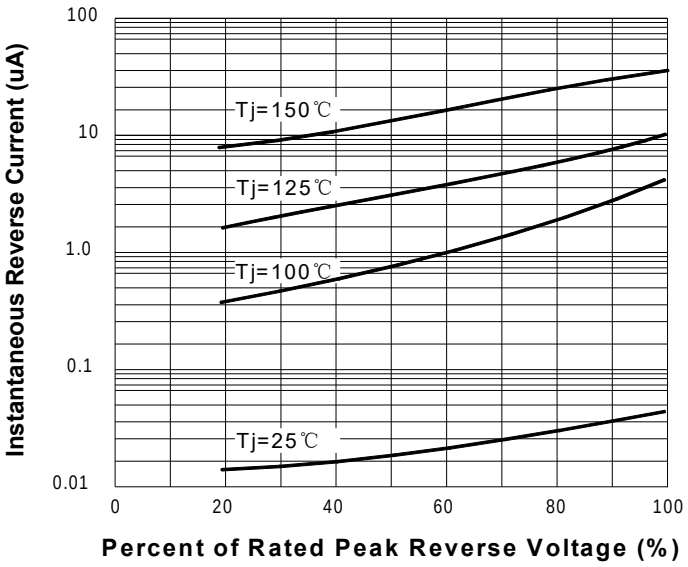
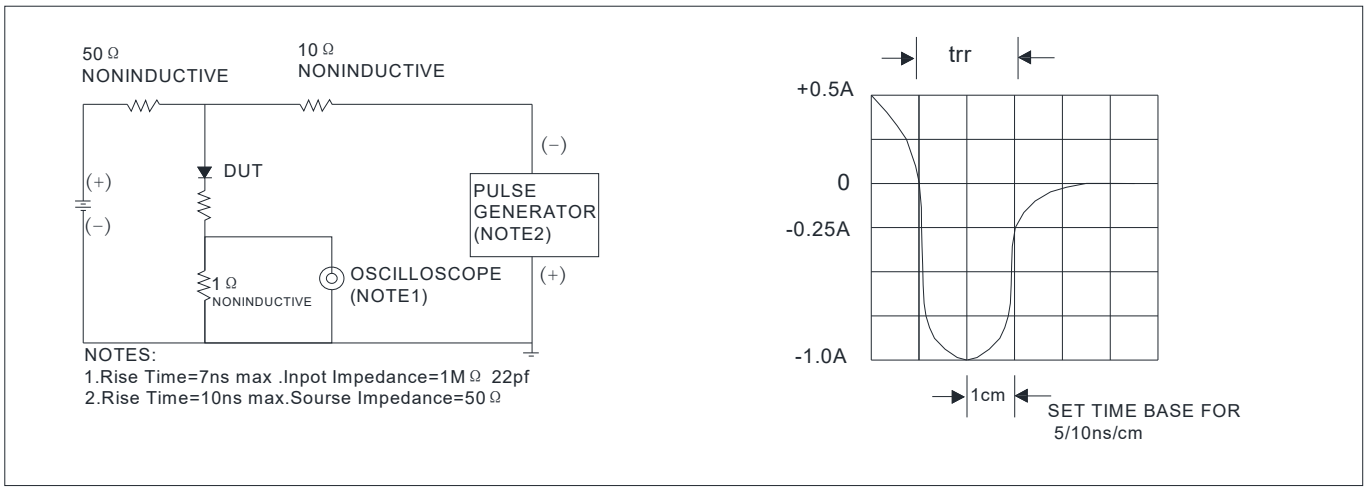
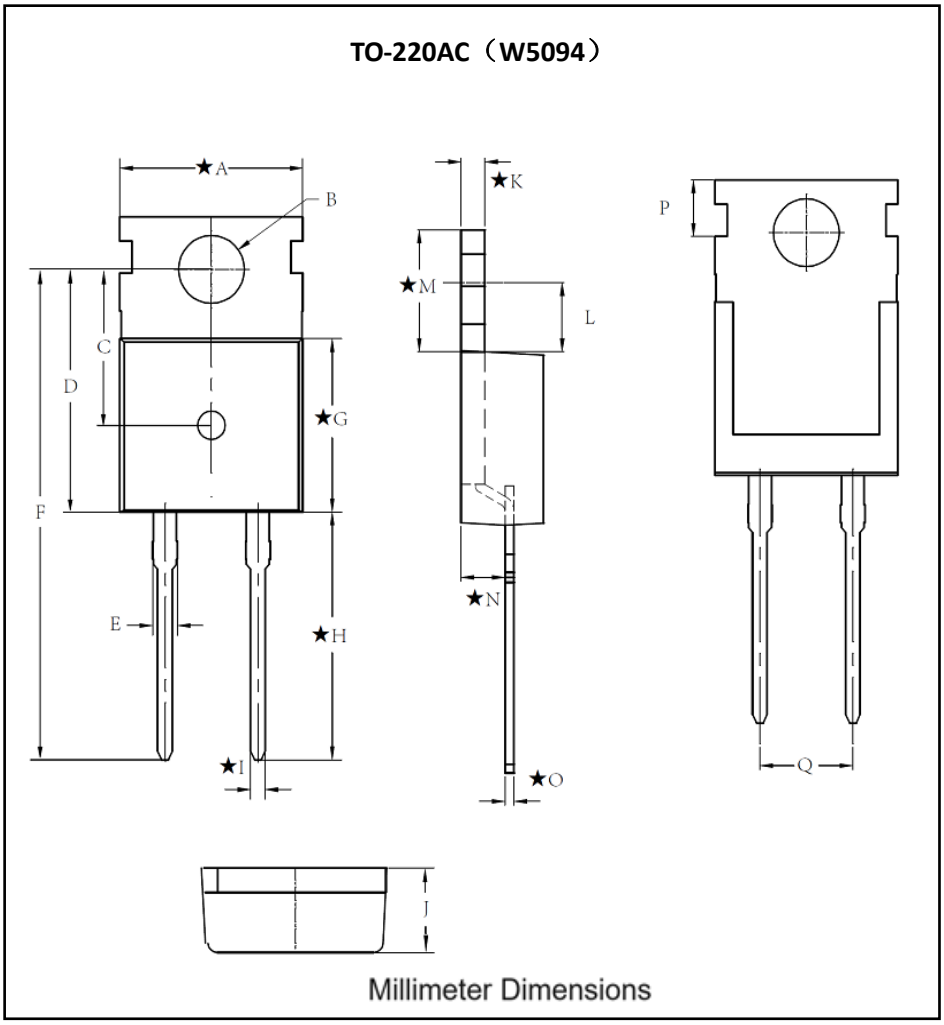


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



■Outline Dimensions



TO-220AC		
Dim	Min	Max
A	9.9	10.1
B	TYP 3.6	
C	8.06	8.46
D	12.67	13.07
E	1.28	1.42
F	25.7	26.3
G	9.0	9.4
H	12.93	13.33
I	TYP 0.8	
J	4.3	4.7
K	1.285	1.315
L	3.47	3.87
M	6.27	6.67
N	2.2	2.6
O	0.485	0.515
P	2.8	3.2
Q	TYP 5.08	

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